

### Low Noise Silicon Bipolar RF Transistor

- For low noise, low distortion broadband amplifiers in antenna and telecommunications systems up to 1.5 GHz at collector currents from 20 mA to 80 mA
- 3 4 1
- Power amplifier for DECT and PCN systems
- $f_T$  = 7.5 GHz,  $NF_{min}$  = 1.3 dB at 900 MHz
- Pb-free (RoHS compliant) package
- Qualification report according to AEC-Q101 available



### ESD (Electrostatic discharge) sensitive device, observe handling precaution!

Туре	Marking	Pin Configuration				Package		
BFP196	RIs	1 = C	2 = E	3 = B	4 = E	-	-	SOT143

### **Maximum Ratings** at $T_A$ = 25 °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Collector-emitter voltage	$V_{CEO}$	12	V
Collector-emitter voltage	$V_{CES}$	20	
Collector-base voltage	$V_{\mathrm{CBO}}$	20	
Emitter-base voltage	$V_{EBO}$	2	
Collector current	I <sub>C</sub>	150	mA
Base current	l <sub>B</sub>	15	
Total power dissipation <sup>1)</sup>	P <sub>tot</sub>	700	mW
<i>T</i> <sub>S</sub> ≤ 77°C			
Junction temperature	$T_{J}$	150	°C
Ambient temperature	$T_{A}$	-65 150	
Storage temperature	T <sub>Stq</sub>	-65 150	

### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>2)</sup>	R <sub>thJS</sub>	105	K/W

<sup>&</sup>lt;sup>1</sup>T<sub>S</sub> is measured on the collector lead at the soldering point to the pcb

<sup>&</sup>lt;sup>2</sup>For the definition of  $R_{thJS}$  please refer to Application Note AN077 (Thermal Resistance Calculation)



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics				•	•
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	12	-	_	V
$I_{\rm C}$ = 1 mA, $I_{\rm B}$ = 0	, ,				
Collector-emitter cutoff current	I <sub>CES</sub>	-	-	100	μΑ
$V_{CE} = 20 \text{ V}, V_{BE} = 0$					
Collector-base cutoff current	I <sub>CBO</sub>	-	-	100	nA
$V_{\rm CB} = 10 \text{ V}, I_{\rm E} = 0$					
Emitter-base cutoff current	I <sub>EBO</sub>	-	-	1	μΑ
$V_{\text{EB}} = 1 \text{ V}, I_{\text{C}} = 0$					
DC current gain	h <sub>FE</sub>	70	100	140	-
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, pulse measured					

2



**Electrical Characteristics** at  $T_A$  = 25 °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics (verified by random sampling	ng)	1	1	· -	
Transition frequency	f <sub>T</sub>	5	7.5	-	GHz
$I_{\rm C}$ = 70 mA, $V_{\rm CE}$ = 8 V, $f$ = 500 MHz					
Collector-base capacitance	C <sub>cb</sub>	-	0.83	1.3	pF
$V_{\text{CB}} = 10 \text{ V}, f = 1 \text{ MHz}, V_{\text{BE}} = 0$ ,					
emitter grounded					
Collector emitter capacitance	C <sub>ce</sub>	-	0.35	-	
$V_{CE} = 10 \text{ V}, f = 1 \text{ MHz}, V_{BE} = 0$ ,					
base grounded					
Emitter-base capacitance	C <sub>eb</sub>	-	3.9	-	
$V_{\text{EB}} = 0.5 \text{ V}, f = 1 \text{ MHz}, V_{\text{CB}} = 0$ ,					
collector grounded					
Minimum noise figure	NF <sub>min</sub>				dB
$I_{\rm C}$ = 20 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt}$ ,					
f = 900 MHz		-	1.3	-	
f = 1.8 GHz		-	2.3	-	
Power gain, maximum available <sup>1)</sup>	G <sub>ma</sub>				
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm Sopt,}$ $Z_{\rm L}$ = $Z_{\rm Lopt}$ ,					
f = 900 MHz		-	16.5	-	
f = 1.8 GHz		-	10.5	-	
Transducer gain	S <sub>21e</sub>   <sup>2</sup>				dB
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 900 MHz		_	13	-	
f = 1.8 GHz		-	7	-	
Third order intercept point at output <sup>2)</sup>	IP <sub>3</sub>	-	32	-	dBm
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,					
f = 0.9 GHz					
1dB Compression point	P <sub>-1dB</sub>	-	19	-	1
$I_{\rm C}$ = 50 mA, $V_{\rm CE}$ = 8 V, $Z_{\rm S}$ = $Z_{\rm L}$ = 50 $\Omega$ ,	""				
f = 0.9 GHz					
			1		

 $<sup>{}^{1}</sup>G_{\text{ma}} = |S_{21} / S_{12}| (k - (k^{2} - 1)^{1/2})$ 

3

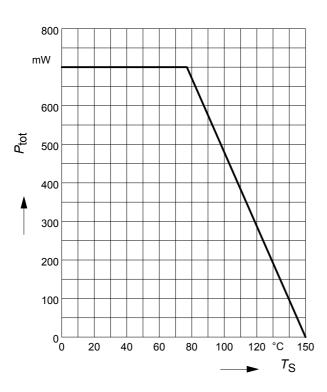
<sup>&</sup>lt;sup>2</sup>IP3 value depends on termination of all intermodulation frequency components.

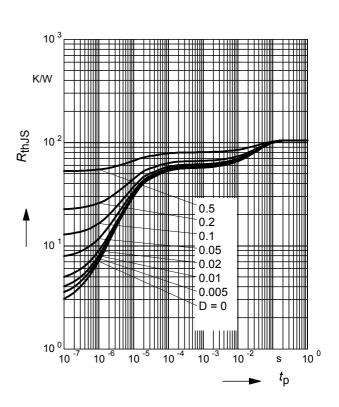
Termination used for this measurement is  $50\Omega$  from 0.2 MHz to 12 GHz



# Total power dissipation $P_{\text{tot}} = f(T_{\text{S}})$

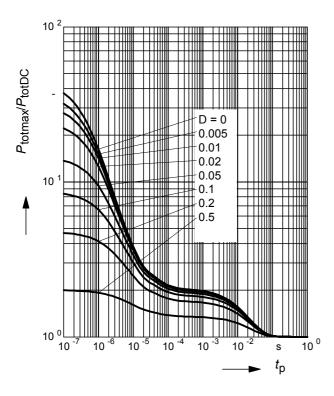
## Permissible Pulse Load $R_{thJS} = f(t_p)$





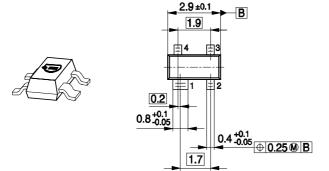
### **Permissible Pulse Load**

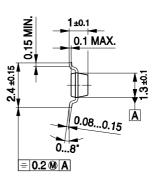
$$P_{\text{totmax}}/P_{\text{totDC}} = f(t_{p})$$





### Package Outline

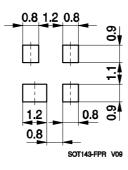




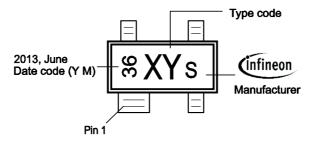
Note: Mold flash, protrusions or gate burrs of 0,2 mm max. per side are not included

SOT143-PO V09

### **Foot Print**

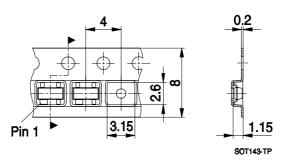


### Marking Layout (Example)



### Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel





Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

© 2009 Infineon Technologies AG All Rights Reserved.

#### **Legal Disclaimer**

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

#### Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (<a href="www.infineon.com">www.infineon.com</a>).

#### Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

单击下面可查看定价,库存,交付和生命周期等信息

>>Infineon Technologies(英飞凌)